



20V P-Channel Enhancement Mode MOSFET

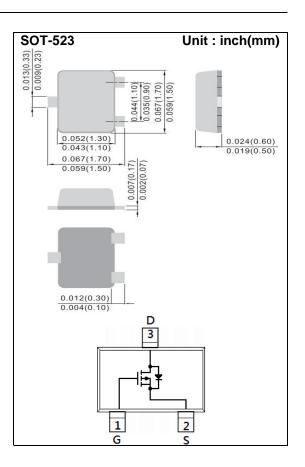
Voltage -20 V Current -0.9A

Features

- RDS(ON), VGS@-4.5V, ID@-0.9A<130mΩ
- RDS(ON) , VGS@-2.5V, ID@-0.6A<160mΩ
- RDS(ON) , VGS@-1.8V, ID@-0.4A<210mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: SOT-523 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.00007 ounces, 0.002 grams
- Marking: E01



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	-20	V
Gate-Source Voltage		V _{GS}	<u>+</u> 12	V
Continuous Drain Current		I _D	-0.9	Α
Pulsed Drain Current		I _{DM}	-3.6	А
Power Dissipation	T _a =25°C	P _D	300	mW
	Derate above 25°C		2.4	mW/°C
Operating Junction and Storage Temperature Range		T_{J} , T_{STG}	-55~150	°C
Typical Thermal resistance - Junction to Ambient (Note 3)		$R_{\theta JA}$	417	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV_{DSS}	V _{GS} =0V, I _D =-250uA	-20	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-250uA$	-0.4	-0.69	-1.2	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-4.5V, I _D =-0.9A	-	110	130	mΩ	
		V _{GS} =-2.5V, I _D =-0.6A	-	130	160		
		V _{GS} =-1.8V, I _D =-0.4A	-	160	210		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-20V, V _{GS} =0V	-	-0.01	-1	uA	
Gate-Source Leakage Current	I_{GSS}	V _{GS} = <u>+</u> 12V, V _{DS} =0V	-	<u>+</u> 10	<u>+</u> 100	nA	
Dynamic							
Total Gate Charge	Q_g	V _{DS} =-10V, I _D =-0.9A, V _{GS} =-4.5V ^(Note 1,2)	-	5.4	-	nC	
Gate-Source Charge	Q_gs		-	0.7	-		
Gate-Drain Charge	Q_gd		-	1.4	-		
Input Capacitance	Ciss	V _{DS} =-10V, V _{GS} =0V, f=1.0MHZ	-	416	-	pF	
Output Capacitance	Coss		-	43	-		
Reverse Transfer Capacitance	Crss	I=I.UIVITZ	-	32	-		
Switching							
Turn-On Delay Time	td _(on)	V_{DD} =-10V, I_{D} =-0.9A, V_{GS} =-4.5V, R_{G} =6 Ω (Note 1,2)	-	4	-	ns	
Turn-On Rise Time	tr		-	27	-		
Turn-Off Delay Time	td _(off)		-	78	-		
Turn-Off Fall Time	tf		-	45	-		
Drain-Source Diode							
Maximum Continuous Drain-Source	Is		-	-	-0.4	Α	
Diode Forward Current	.3				J		
Diode Forward Voltage	V_{SD}	I _S =-1A, V _{GS} =0V	-	-0.8	-1.2	V	

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





TYPICAL CHARACTERISTIC CURVES

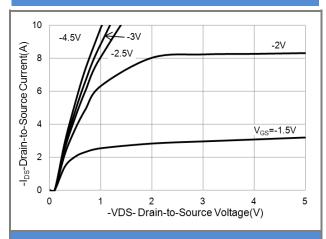


Fig.1 On-Region Characteristics

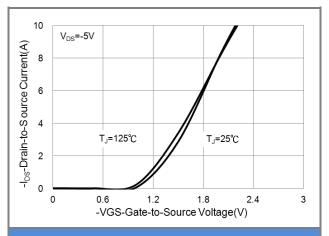


Fig.2 Transfer Characteristics

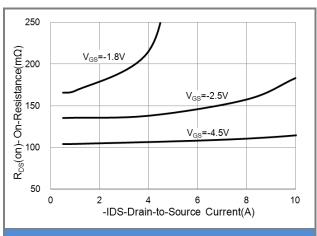


Fig.3 On-Resistance vs. Drain Current

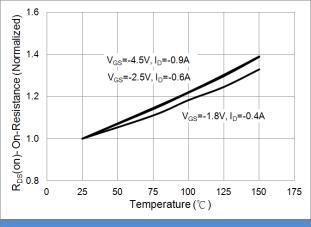
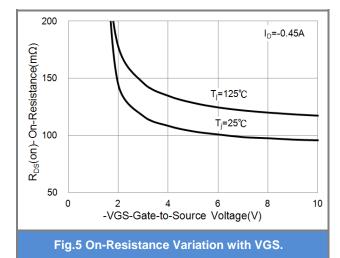
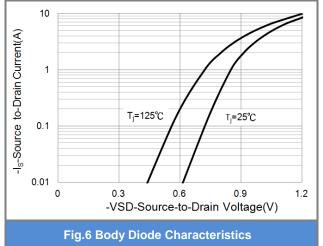


Fig.4 On-Resistance vs. Junction temperature









TYPICAL CHARACTERISTIC CURVES

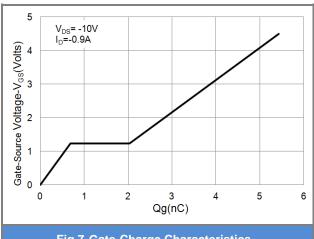


Fig.7 Gate-Charge Characteristics

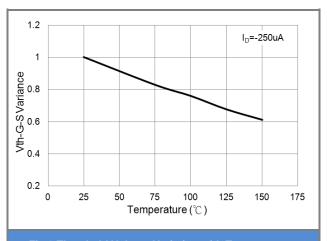


Fig.8 Threshold Voltage Variation with Temperature

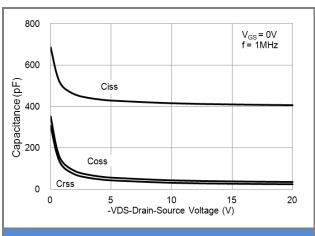


Fig.9 Capacitance vs. Drain-Source Voltage

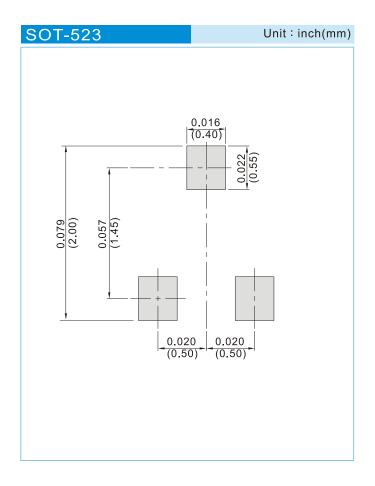




PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJE8401_R1_00001	SOT-523	4K pcs / 7" reel	E01	Halogen free

MOUNTING PAD LAYOUT



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